NSN 5961-01-245-4857

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-245-4857 **Inclosure Material:** Metal **Overall Length:** Between 0.188 inches and 0.208 inches **Overall Diameter:** Between 0.119 inches and 0.127 inches **End Application:** F-15 acft **Mounting Facility Quantity: Mounting Method:** Threaded stud **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, dc **Power Rating Per Characteristic:** 250.0 milliwatts large-signal output power, common-collector universal **Maximum Operating Tempurature Per Measurement Point:** 71.0 degrees celsius case **Precious Material And Location:** Terminals plated gold **Test Data Document:** 82577-925194 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing) **Terminal Type And Quantity:** 2 case Shelf Life: N/a **Unit Of Measure: Demilitarization:** No